

Docket No. 211897US99



2814

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN RE APPLICATION OF: Robert J. HIGGINS, et al.

SERIAL NO: 09/911,496

GAU: 2814

FILED: July 25, 2001

EXAMINER: WILLE

FOR: MONOLITHIC SEMICONDUCTOR-PIEZOELECTRIC DEVICE STRUCTURES AND ELECTRO-ACOUSTIC
CHARGE TRANSPORT DEVICES

INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR §1.97

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

Applicant(s) wish to disclose the following information.

REFERENCES

- The applicant(s) wish to make of record the references listed on the attached form PTO-1449. Copies of the listed references were submitted in application Serial No. 09/908,888 according to the attached copy of a Granted Petition. This application contains related subject matter.
- A check or credit card payment form is attached in the amount required under 37 CFR §1.17(p).

RELATED CASES

- Attached is a list of applicant's pending application(s) or issued patent(s) which may be related to the present application. A copy of the patent(s), together with a copy of the claims and drawings of the pending application(s) is attached along with PTO 1449.
- A check or credit card payment form is attached in the amount required under 37 CFR §1.17(p).

CERTIFICATION

- Each item of information contained in this information disclosure statement was first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this statement.
- No item of information contained in this information disclosure statement was cited in a communication from a foreign patent office in a counterpart foreign application or, to the knowledge of the undersigned, having made reasonable inquiry, was known to any individual designated in 37 CFR §1.56(c) more than three months prior to the filing of this statement.

DEPOSIT ACCOUNT

- Please charge any additional fees for the papers being filed herewith and for which no check or credit card payment is enclosed herewith, or credit any overpayment to deposit account number 15-0030. A duplicate copy of this sheet is enclosed.

Respectfully submitted,

OBLON, SPIVAK, McCLELLAND,
MAIER & NEUSTADT, P.C.

Richard L. Treanor
Registration No. 36,379

Customer Number

22850

Tel. (703) 413-3000
Fax. (703) 413-2220
(OSMMN 05/03)

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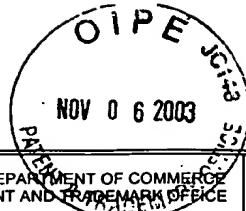
Form PTO 1449 (Modified)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY DOCKET NO. 211897US99	SERIAL NO. 09/911,496		
		LIST OF REFERENCES CITED BY APPLICANT		APPLICANT Robert J. HIGGINS, et al.			
				FILING DATE July 25, 2001	GROUP 2814		
				U.S. PATENT DOCUMENTS			
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE	
XN	6,233,435 B1	05/15/01	WONG				
XO	4,723,321	02/02/88	SALEH				
XP	6,181,920 B1	01/30/01	DENT ET AL				
XQ	6,415,140 B1	07/02/02	BENJAMIN ET AL				
XR	5,760,740	06/02/98	BLODGETT				
XS	5,238,877	08/24/93	RUSSELL				
XT	4,876,218	10/24/89	PESSA ET AL				
XU	6,232,242 B1	05/15/01	HATA ET AL				
XV	4,378,259	03/29/83	HASEGAWA ET AL				
XW	6,278,541 B1	08/21/01	BAKER				
XY	4,298,247	11/03/81	MICHELET ET AL				
XZ	4,174,504	11/13/79	CHENAUSKY ET AL				
YA	3,758,199	09/11/73	THAXTER				
YB	6,362,558 B1	03/26/02	FUKUI				
YC	6,140,746	10/31/00	MIYASHITA ET AL				
YD	2002/0076878 A1	06/20/02	WASA ET AL				
YE	6,419,849 B1	07/16/02	QIU ET AL				
YF	2002/0179000 A1	12/05/02	LEE ET AL				
YG	6,341,851	01/29/02	TAKAYAMA ET AL				
YH	2001/0055820 A1	12/27/01	SAKURAI ET AL				
YI	6,204,525 B1	03/20/01	SAKURAI ET AL				
YJ	5,985,404	11/16/99	YANO ET AL				
YK	6,538,359 B1	03/25/03	HIRAKU ET AL				
YL	6,498,358 B1	12/24/02	LACH ET AL				
YM	5,387,811	02/07/95	SAIGOH				
YN	5,523,602	06/04/96	HORIUCHI ET AL				
YO	5,362,998	11/08/94	IWAMURA ET AL				
YP	5,188,976	02/23/93	KUME ET AL				
Examiner				Date Considered			
*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							

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U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
	YQ	6,501,121 B1	12/31/02	YU ET AL			NOV 14 2003
	YR	5,919,515	07/06/99	YANO ET AL			
	YS	5,238,877	08/24/93	RUSSELL			
	YT	5,540,785	07/30/96	DENNARD ET AL			
	YU	5,997,638	12/07/99	COPEL ET AL			
	YV	6,291,866	09/18/01	WALLACE			
	YW	5,365,477	11/15/94	COOPER, JR ET AL			
	YX	5,548,141	08/20/96	MORRIS ET AL			
	YY	2002/0021855	02/21/02	KIM			
	YZ	6,110,840	08/29/00	YU			
	ZA	5,667,586	09/16/97	EK ET AL			
	ZB	5,313,058	05/17/94	FRIEDERICH ET AL			
	ZC	5,315,128	05/24/94	HUNT ET AL			
	ZD	5,919,522	07/06/99	BAUM ET AL			
	ZE	4,843,609	06/27/89	OHYA ET AL			
	ZF	4,626,878	12/02/86	KUWANO ET AL			
	ZG	4,525,871	06/25/85	FOYT ET AL			
	ZH	3,818,451	06/18/74	COLEMAN			
	ZI	6,059,895	05/09/00	CHU ET AL			
	ZJ	4,447,116	05/08/84	KING ET AL			
	ZK	6,022,671	02/08/00	BINKLEY ET AL			
	ZL	5,754,714	05/19/98	SUZUKI ET AL			
	ZM	6,524,651 B2	02/25/03	GAN ET AL			
	ZN	6,355,945 B1	03/12/03	KADOTA ET AL			
	ZO	5,642,371	06/24/97	TOHYAMA ET AL			
	ZP	6,445,724 B2	09/03/02	ABELES			
	ZQ	5,753,934	05/19/98	YANO ET AL			
	ZR	6,326,667 B1	12/04/01	SUGIYAMA ET AL			
	ZS	6,051,874	04/18/00	MASUDA			
	ZT	5,166,761	11/24/92	OLSON ET AL			
	ZU	5,574,744	11/12/96	GAW ET AL			
Examiner					Date Considered		

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FOREIGN PATENT DOCUMENTS					
		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION YES NO
	CCA	5-238894	09/17/93	JAPAN W/ENGLISH ABSTRACT	
	CCB	2 152 315	07/31/85	GREAT BRITAIN	
	CCC	2001-196892	07/19/01	JAPAN W/ENGLISH ABSTRACT	
	CCD	2000-278085	10/06/00	JAPAN (ENGLISH ABSTRACT)	
	CCE	WO 03/012874	02/13/03	WIPO	
	CCF	1 043 427	10/11/00	EUROPE	
	CCG	1 069 605	01/17/01	EUROPE	
	CCH	WO 02/099885	12/12/02	WIPO	
	CCI	10-269842	10/09/98	JAPAN W/ENGLISH ABSTRACT	
	CCJ	59066183	04/14/84	JAPAN (ENGLISH ABSTRACT)	
	CCK	03046384	02/27/91	JAPAN (ENGLISH ABSTRACT)	
	CCL	WO 02/11254	02/07/02	WIPO	
	CCM	0 494 514	07/15/92	EUROPE	
	CCN	0 247 722	12/02/87	EUROPE	
	CCO	1 037 272	09/20/00	EUROPE	
	CCP	59-073498	04/25/84	JAPAN (ENGLISH ABSTRACT)	
	CCQ	60-161635	08/23/85	JAPAN W/ENGLISH ABSTRACT	
	CCR	59-044004	03/12/84	JAPAN W/ENGLISH ABSTRACT	
	CCS	0 392 714	10/17/90	EUROPE	
	CCT				
	CCU				
	CCV				
	CCW				
	CCX				
	CCY				
	CCZ				
	CDA				
	CDB				
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OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)				
LLAA	Peter Weiss; "Speed demon gets hooked on silicon"; Science News Online; Sept. 15, 2001; pp. 1-3			
LLAB	"Motorola Develops New Super-Fast Chip"; USA Today; Sept. 4, 2001			
LLAC	Lori Valigra; "Motorola Lays GaAs on Si Wafer"; AsiaBizTech; Nov. 2001pp. 1-3			
LLAD	"Holy Grail! Motorola Claims High-Yield GaAs Breakthrough"; Micromagazine.com (no date available); pp. 1-3			
LLAE	Jong-Gul YOON; "Growth of Ferroelectric LiNbO ₃ Thin Film on MgO-Buffered Si by the Sol-Gel Method"; Journal of the Korean Physical Society (Proc. Suppl.); Vol. 29, Nov. 1996; pp. S648-S651			
LLAF	V. Bornand et al.; "Deposition of LiTaO ₃ thin films by pyrosol process"; Thin Solid Films 304 (1997); pp.239-244			
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LLAI	Dwight C. Streit et al; "High Reliability GaAs-AlGaAs HBT's by MBE with Be Base Doping and InGaAs Emitter Contacts"; 8179 Ieee Electron Device Letters; 12(1991) September, No. 9, New York, US			
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LLAK	J. Piprek; "Heat Flow Analysis of Long-Wavelength VCSELs with Various DBR Materials"; University of Delaware, Materials Science, Newark, DE, 19716-3106; Oct. 31, 1994; pp. 286-287			
LLAL	P. Mackowiak et al.; "Some aspects of designing an efficient nitride VCSEL resonator"; J. Phys. D: Appl. Phys. 34(2001); pp. 954-958			
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LLAN	Y. Kitano et al.; "Thin film crystal growth of BaZrO ₃ at low oxygen partial pressure"; Journal of Crystal Growth 243 (2002); pp. 164-169			
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LLAP				
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